



# RS3ABF THRU RS3MBF

## SURFACE MOUNT FAST RECOVERY RECTIFIER

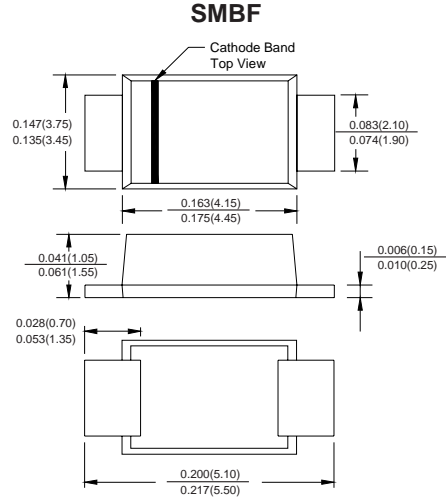
Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Ampere

### FEATURES

The plastic package carries Underwriters Laboratory Flammability Classification 94V-0  
 For surface mounted applications  
 Fast switching for high efficiency  
 Low reverse leakage  
 Built-in strain relief, ideal for automated placement  
 High forward surge current capability  
 High temperature soldering guaranteed:  
 260°C/10 seconds at terminals  
 Glass passivated chip junction

### MECHANICAL DATA

**Case:** SMBF molded plastic body over passivated chip  
**Terminals:** Solder plated, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.002 ounce, 0.056 grams



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	RS3ABF	RS3BBF	RS3DBF	RS3GBF	RS3JBF	RS3KBF	RS3MBF	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at $T_L=100^\circ\text{C}$	$I_{(AV)}$	3.0							A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	100							A
Maximum instantaneous forward voltage at 3.0A	$V_F$	1.3							V
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$	$I_R$	5.0 200.0							$\mu\text{A}$
Maximum reverse recovery time (NOTE 1)	$t_{rr}$	150				250	500		ns
Typical junction capacitance (NOTE 2)	$C_J$	60.0							pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$	78.0							$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	$T_J, T_{STG}$	-55 to +150							$^\circ\text{C}$

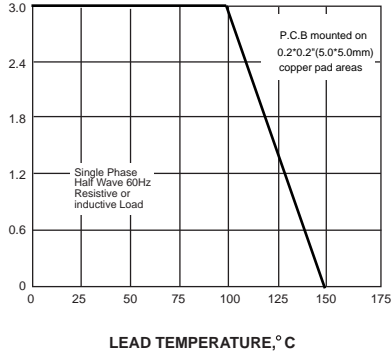
**Note:** 1. Reverse recovery condition  $I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$   
 2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 3. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



# RATINGS AND CHARACTERISTIC CURVES RS3ABF THRU RS3MBF

AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

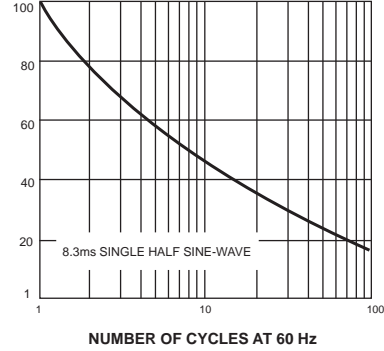


FIG. 3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

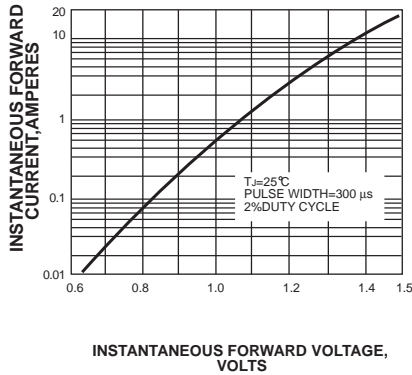


FIG. 4- TYPICAL REVERSE CHARACTERISTICS

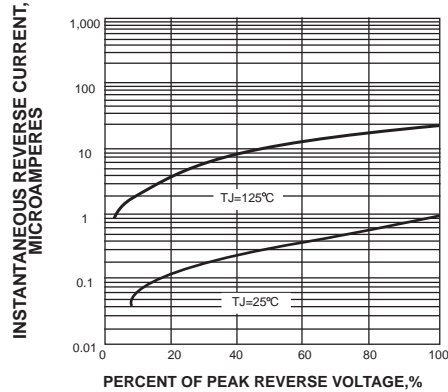
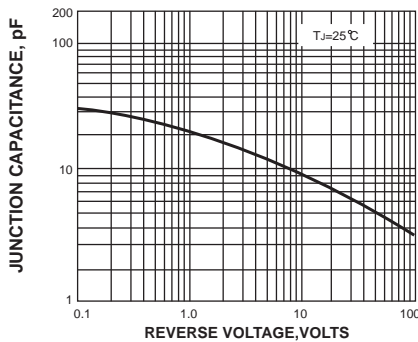
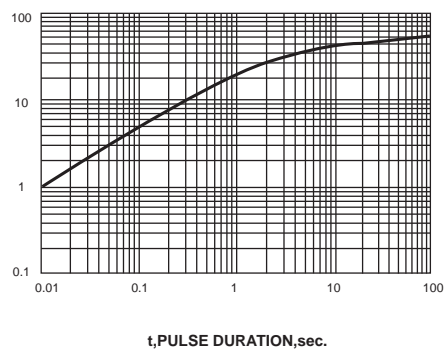


FIG. 5- TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6- TYPICAL TRANSIENT THERMAL IMPEDANCE



单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)